

2SC3707

Silicon NPN epitaxial planar type

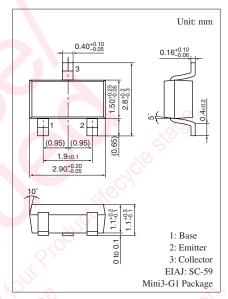
For UHF amplification

■ Features

- Possible with the small current and low voltage
- High transition frequency f_T
- Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing and the magazine packing

■ Absolute Maximum Ratings $T_a = 25^{\circ}C$

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V_{CBO}	10	V	
Collector-emitter voltage (Base open)	V_{CEO}	7	V	
Emitter-base voltage (Collector open)	V _{EBO}	2	V	
Collector current	I_{C}	10	mA	
Collector power dissipation	P_{C}	50	mW	
Junction temperature	T _j	150	°C	
Storage temperature	T_{stg}	-55 to +150	°C	



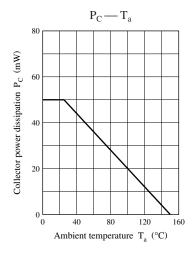
Marking Symbol: 2X

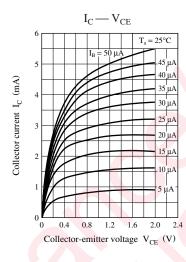
■ Electrical Characteristics $T_a = 25$ °C ± 3°C

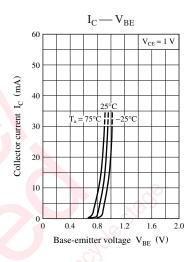
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = 10 \text{ V}, I_{E} = 0$		S S	1	μΑ
Emitter-base cutoff current (Collector open)	I_{EBO}	$V_{EB} = 1.5 \text{ V}, I_C = 0$		0,	1	μΑ
Forward current transfer ratio	h_{FE}	$V_{CE} = 1 \text{ V}, I_C = 1 \text{ mA}$	50		150	
Transition frequency	f_T	$V_{CE} = 1 \text{ V}, I_C = 1 \text{ mA}, f = 0.8 \text{ GHz}$		4		GHz
Collector output capacitance	C _{ob}	$V_{CB} = 1 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$		0.4		pF
(Common base, input open circuited)		110, 50,				
Forward transfer gain	$ S_{21e} ^2$	$V_{CE} = 1 \text{ V}, I_{C} = 1 \text{ mA}, f = 0.8 \text{ GHz}$		6.0		dB
Maximum unilateral power gain	G_{UM}	$V_{CE} = 1 \text{ V}, I_{C} = 1 \text{ mA}, f = 0.8 \text{ GHz}$		15		dB
Noise figure	NF	$V_{CE} = 1 \text{ V}, I_{C} = 1 \text{ mA}, f = 0.8 \text{ GHz}$		3.5		dB

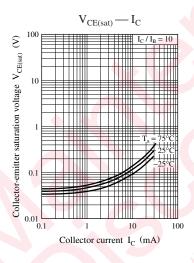
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

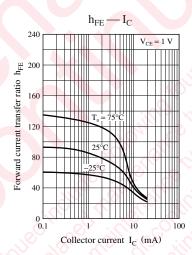
^{2.} Handle the product with care because this is sensitive to the electrostatic breakdown by its structure

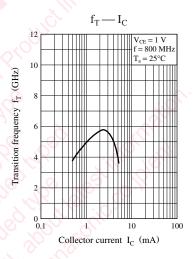


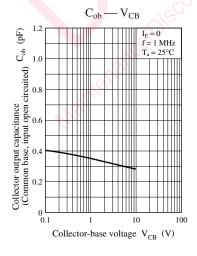


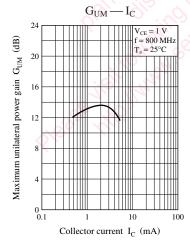


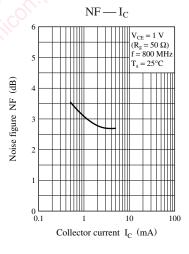












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